

Dual Inverter Gate

General Description

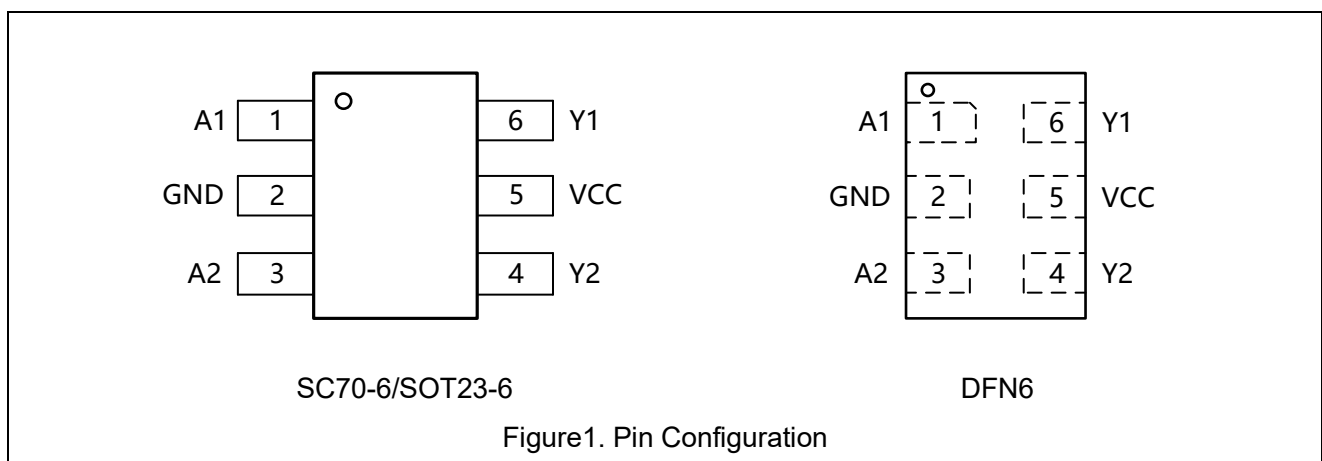
The ET74LVC2G04 is a high-performance dual inverter operating from a 1.65V to 5.5V supply. This device is fabricated with advanced CMOS technology to achieve ultra-high speed with high output drive.

Features

- Designed for 1.65V to 5.5V V_{CC} Operation
- Over-voltage Tolerant Inputs Accept Voltages to 5.5V
- $\pm 32\text{mA}$ Balanced Output Sink and Source Capability
- Near Zero Static Supply Current Substantially Reduces System Power Requirements
- These Devices are Pb-Free and RoHS Compliant
- ESD Protection Complies with JESD22 Standard
 - HBM: $\pm 4000\text{V}$ Pass (JEDEC JS-001)
 - CDM: $\pm 1000\text{V}$ Pass (JEDEC JS-002)
- Latch-up Performance Exceeds $\pm 100\text{mA}$ per JEDEC JESD78F
- Part No. and Package Information

Part No.	Package	Packing Option	MSL
ET74LVC2G04	SC70-6 (1.3mm $\times$ 2.1mm)	Tape and Reel, 3K/Reel	1
ET74LVC2G04T	SOT23-6 (1.6mm $\times$ 2.9mm)	Tape and Reel, 3K/Reel	3
ET74LVC2G04Y	DFN6 (1.0mm $\times$ 1.5mm)	Tape and Reel, 3K/Reel	1

Pin Configuration



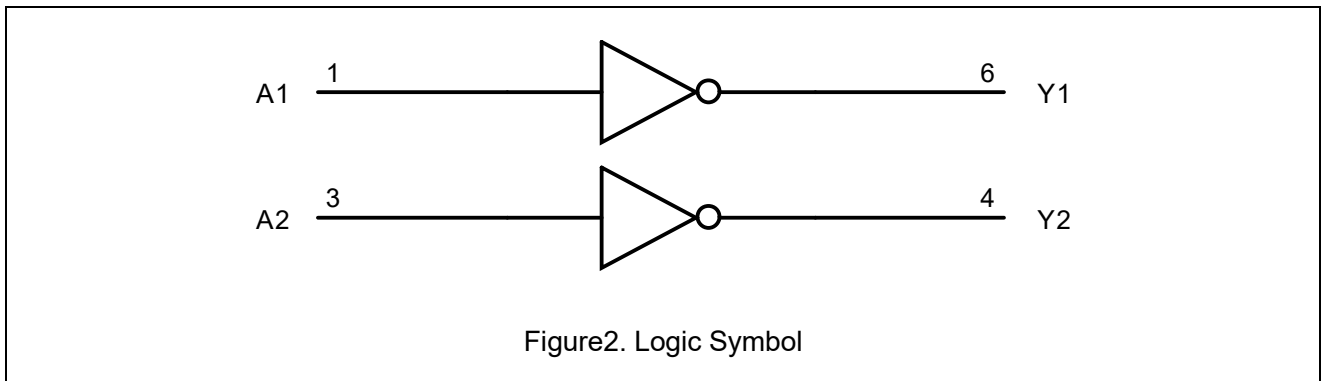
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Pin Function

SC70-6/ SOT23-6/ DFN6

Pin No.	Pin Name	Function
1	A1	Input CH1
2	GND	Ground
3	A2	Input CH2
4	Y2	Output CH2
5	VCC	Supply Voltage
6	Y1	Output CH1

Block Diagram



Functional Table

Input A	Output Y
L	H
H	L

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Absolute Maximum Ratings

Symbol	Parameter		Value	Unit
V_{CC}	DC Supply Voltage		-0.5 to 6.5	V
V_I	DC Input Voltage ⁽¹⁾		$-0.5 \leq V_I \leq 6.5$	V
V_O	DC Output Voltage Output in Higher or Low State		-0.5 to $V_{CC} + 0.5$	V
I_{IK}	DC Input Diode Current $V_I < GND$		-50	mA
I_{OK}	DC Output Diode Current $V_O < GND$		± 50	mA
I_O	DC Output Sink Current		± 50	mA
I_{CC}	DC Supply Current per Supply Pin		100	mA
I_{GND}	DC Ground Current per Supply Pin		-100	mA
T_{STG}	Storage Temperature Range		-65 to 150	°C
T_L	Lead Temperature, Soldering 10 Seconds		260	°C
T_J	Max Junction Temperature		150	°C
V_{ESD}	ESD Classification	Human Body Model ⁽²⁾	± 4000	V
		Charged Device Model ⁽³⁾	± 1000	
I_{LU}	Max Latch Up Current Above V_{CC} and GND at 125°C ⁽⁴⁾		± 100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Note1: I_O absolute maximum rating must be observed.

Note2: HBM tested per JEDEC JS-001;

Note3: CDM tested per JEDEC JS-002;

Note4: Latch Up Current Maximum Rating tested per JEDEC JESD78F.

Thermal Characteristics

Symbol	Package	Ratings	Value	Unit
$R_{\theta JA}$	SC70-6	Thermal Characteristics, Thermal Resistance, Junction-to-Air	280	°C/W
	SOT23-6		180	
	DFN6		440	
P_D	SC70-6	Power Dissipation in Still Air at 85°C	230	mW
	SOT23-6		360	
	DFN6		150	

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Recommended Operating Conditions

Symbol	Parameter		Min	Max	Unit
V _{CC}	DC Supply Voltage		1.65	5.5	V
	Operating Date Retention		1.5	5.5	
V _I	DC Input Voltage		0	V _{CC}	V
V _O	DC Output Voltage (High or Low State)		0	V _{CC}	V
T _A	Operating Temperature Range		-40	125	°C
t _r , t _f	Input Rise and Fall Time	V _{CC} = 2.5V ± 0.2V	0	20	ns/V
		V _{CC} = 3.0V ± 0.3V	0	10	
		V _{CC} = 5.0V ± 0.5V	0	5	

Electrical Characteristics

DC Electrical Characteristics

Symbol	Parameter	Condition	V _{CC} (V)	T _A = 25°C			-40°C ≤ T _A ≤ 125°C		Unit
				Min	Typ	Max	Min	Max	
V _{IH}	High-Level Input Voltage		1.65~1.95	0.75V _{CC}			0.75V _{CC}		V
			2.3~5.5	0.7V _{CC}			0.7V _{CC}		
V _{IL}	Low-Level Input Voltage		1.65~1.95			0.25V _C c		0.25V _{CC}	V
			2.3~5.5			0.3V _{CC}		0.3V _{CC}	
V _{OH}	High-Level Output Voltage	I _{OH} = -100uA	1.65~5.5	V _{CC} - 0.1	V _{CC}		V _{CC} - 0.1		V
		I _{OH} = -4mA	1.65	1.29	1.4		1.29		
		I _{OH} = -8mA	2.3	1.9	2.1		1.9		
		I _{OH} = -12mA	2.7	2.2	2.4		2.2		
		I _{OH} = -16mA	3.0	2.4	2.7		2.4		
		I _{OH} = -24mA	3.0	2.3	2.5		2.3		
V _{OL}	Low-Level Output Voltage	I _{OL} = 100uA	1.65~5.5		0.0	0.1		0.1	V
		I _{OL} = 4mA	1.65		0.08	0.24		0.24	
		I _{OL} = 8mA	2.3		0.20	0.3		0.3	
		I _{OL} = 12mA	2.7		0.22	0.4		0.4	
		I _{OL} = 16mA	3.0		0.28	0.4		0.4	
		I _{OL} = 24mA	3.0		0.38	0.55		0.55	
		I _{OL} = 32mA	4.5		0.42	0.55		0.55	
I _I	Input Leakage Current	V _I = 5.5V or GND	0~5.5			±0.1		±1.0	uA

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DC Electrical Characteristics(Continued)

Symbol	Parameter	Condition	V _{CC} (V)	T _A = 25°C			-40°C ≤ T _A ≤ 125°C		Unit
				Min	Typ	Max	Min	Max	
I _{OFF}	Power Off Leakage Current	V _I = 5.5V or V _O = 5.5V	0			1		10	uA
I _{CC}	Quiescent Supply Current	V _I = 5.5V or GND	1.65~5.5			1		10	uA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC Electrical Characteristics

t_r = t_f = 3ns

Symbol	Parameter	Condition	V _{CC} (V)	T _A = 25°C			-40°C ≤ T _A ≤ 125°C		Unit
				Min	Typ	Max	Min	Max	
t _{pd}	Propagation Delay (Figure 3 and 4)	R _L = 1kΩ; C _L = 30pF	1.65~1.95		11.4	14.8		16.8	ns
		R _L = 500Ω; C _L = 30pF	2.3~2.7		6.2	8		10	
		R _L = 500Ω; C _L = 50pF	2.7		5.8	7.5		9.5	
		R _L = 500Ω; C _L = 50pF	3.0~3.6		5.4	7		9	
		R _L = 500Ω; C _L = 50pF	4.5~5.5		3.9	5.1		7.1	

Capacitance Characteristics

Symbol	Parameter	Condition	Typ	Unit
C _{IN}	Input Capacitance	V _{CC} = 5.5V, V _I = 0V or V _{CC}	2	pF
C _{PD}	Power Dissipation Capacitance ⁽⁵⁾	10MHz, V _{CC} = 3.3V, V _I = 0V or V _{CC}	21	pF
		10MHz, V _{CC} = 5.5V, V _I = 0V or V _{CC}	24	

Note5: C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

Σ(C_L × V_{CC}² × f_o) = sum of outputs.

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AC Test Circuit

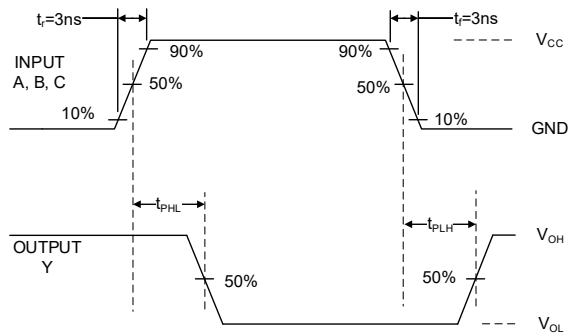


Figure3. Switching Waveform

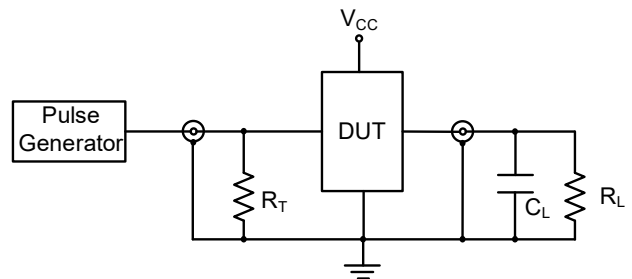
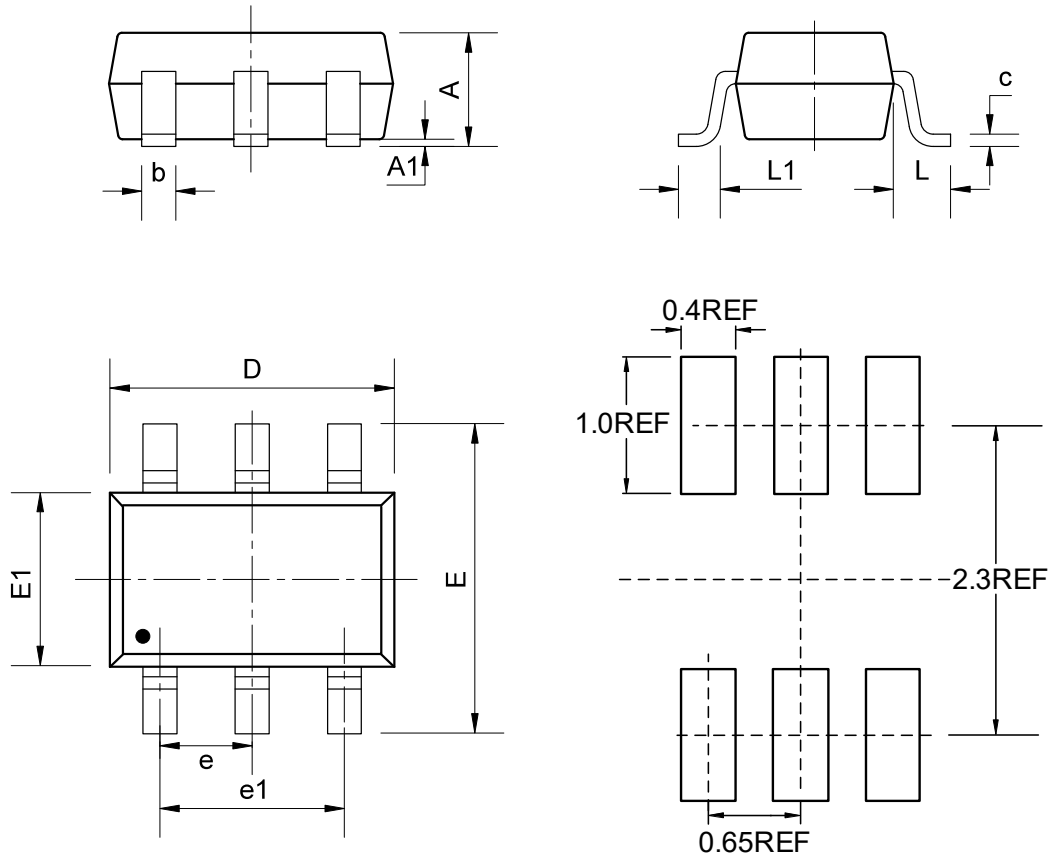


Figure4. Test Circuit

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Package Dimension

SC70-6 (1.3mm × 2.1mm)



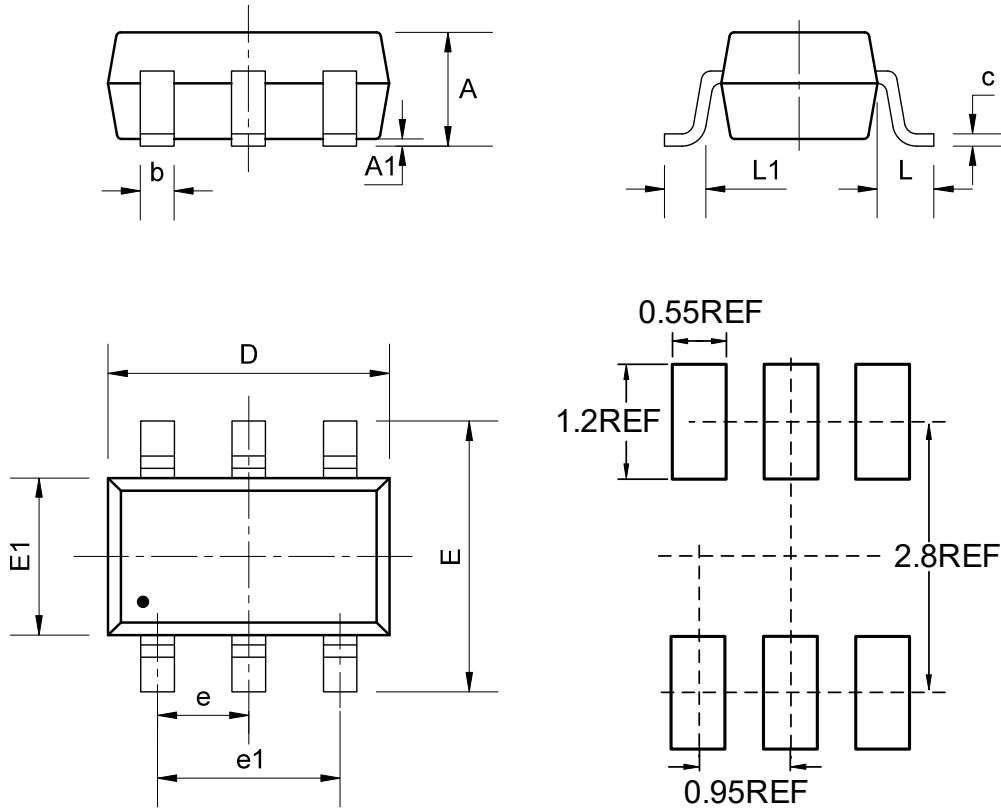
COMMON DIMENSIONS

(Unit: mm)

SYMBOL	MIN	NOM	MAX
A	-	-	1.10
A1	0.00	-	0.15
b	0.15	-	0.35
c	0.08	-	0.20
D	2.00	2.10	2.30
e	0.65BSC		
e1	1.30BSC		
E	2.15	2.30	2.50
E1	1.15	1.30	1.45
L	0.50REF		
L1	0.33REF		

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SOT23-6 (1.6mm × 2.9mm)



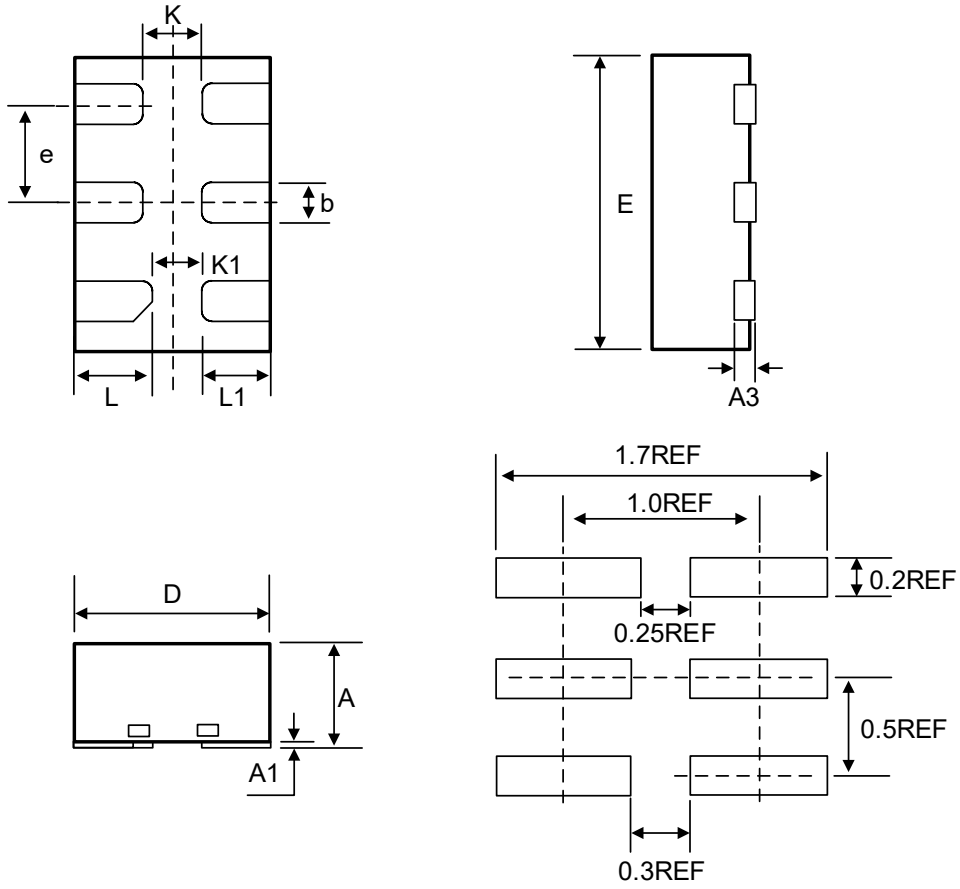
COMMON DIMENSIONS

(Unit: mm)

SYMBOL	MIN	NOM	MAX
A	-	-	1.45
A1	0.00	-	0.15
b	0.28	0.35	0.50
c	0.08	0.15	0.22
D	2.75	2.9	3.05
e	0.90	0.95	1.00
e1	1.80	1.90	2.00
E	2.60	2.80	3.00
E1	1.45	1.6	1.75
L	0.60REF		
L1	0.30	0.45	0.60

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DFN6 (1.0mm × 1.5mm)



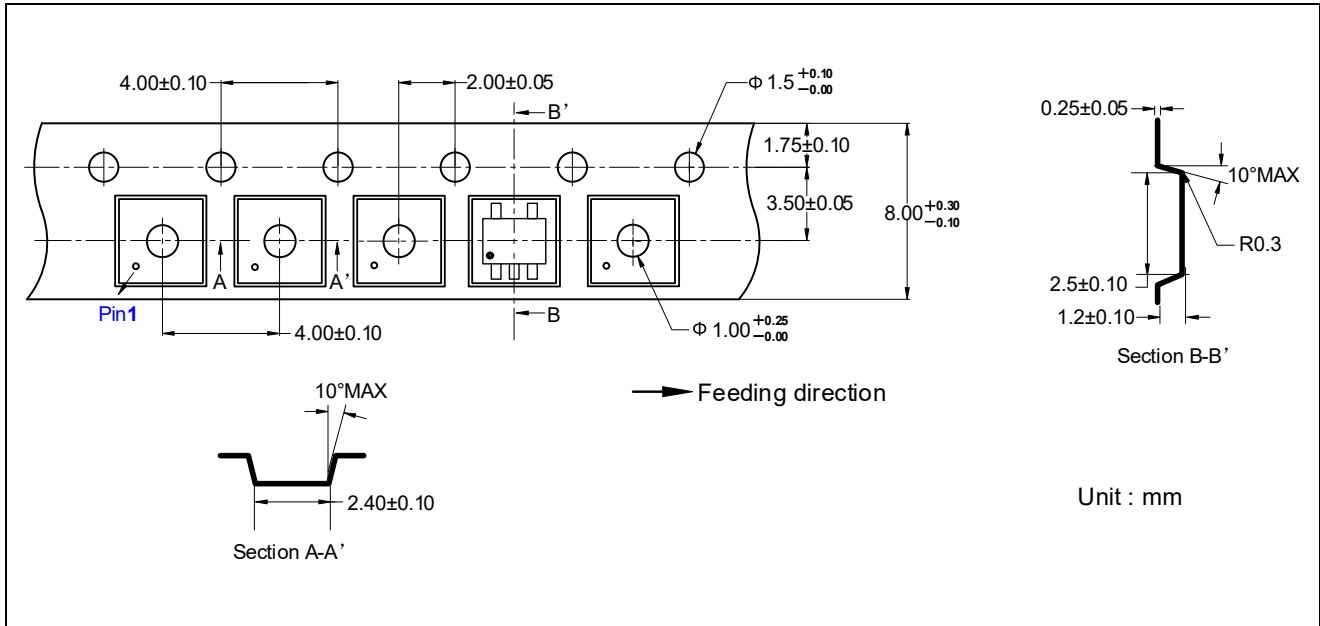
COMMON DIMENSIONS
(Unit: mm)

SYMBOL	MIN	NOM	MAX
A	0.5	--	0.6
A1	0.00	0.02	0.05
A3	0.10REF		
b	0.15	0.20	0.25
D	0.90	1.00	1.10
E	1.40	1.50	1.60
e	0.50BSC		
K	0.30REF		
K1	0.25REF		
L	0.35	0.40	0.45
L1	0.30	0.35	0.40

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Tape Information

SC70-6 (1.3mm × 2.1mm)



SOT23-6 (1.6mm × 2.9mm)

